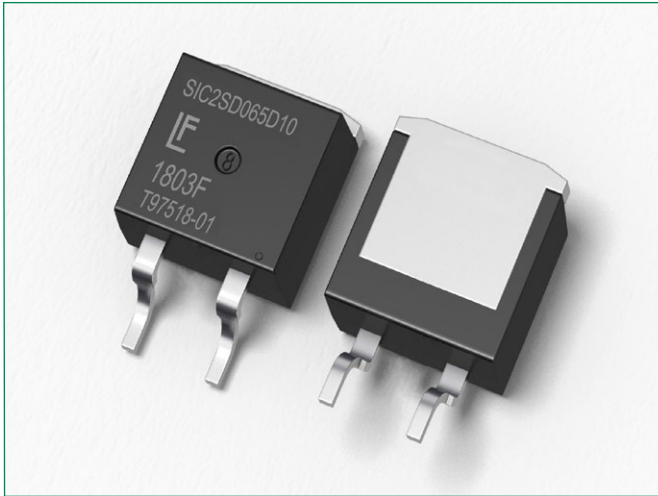


GEN2 SiC Schottky Diode

LSIC2SD065D10A, 650 V, 10 A, TO-263-2L (D2PAK)

LSIC2SD065D10A 650 V, 10 A SiC Schottky Barrier Diode



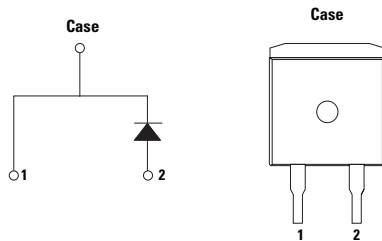
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-263-2L



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	650	V
DC Blocking Voltage	V_R	$T_J = 25\text{ °C}$	650	V
Continuous Forward Current	I_F	$T_C = 25\text{ °C}$	27	A
		$T_C = 135\text{ °C}$	12.5	
		$T_C = 147\text{ °C}$	10	
Non-Repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ °C}, T_P = 10\text{ ms}, \text{Half sine pulse}$	48	A
Power Dissipation	P_{Tot}	$T_C = 25\text{ °C}$	100	W
		$T_C = 110\text{ °C}$	43	
Operating Junction Temperature	T_J	-	-55 to 175	°C
Storage Temperature	T_{STG}	-	-55 to 150	°C
Soldering Temperature	T_{SOLD}	-	260	°C

Electrical Characteristics ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F = 10\text{ A}, T_J = 25\text{ }^{\circ}\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	-	1.85	-	
Reverse Current	I_R	$V_R = 650\text{ V}, T_J = 25\text{ }^{\circ}\text{C}$	-	<1	50	μA
		$V_R = 650\text{ V}, T_J = 175\text{ }^{\circ}\text{C}$	-	25	-	
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	470	-	pF
		$V_R = 200\text{ V}, f = 1\text{ MHz}$	-	60	-	
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	43	-	
Total Capacitive Charge	Q_C	$V_R = 400\text{ V}, Q_C = \int_0^{V_R} C(V) dV$	-	30	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance	$R_{\theta JC}$	1.5	$^{\circ}\text{C/W}$

Figure 1: Typical Forward Characteristics

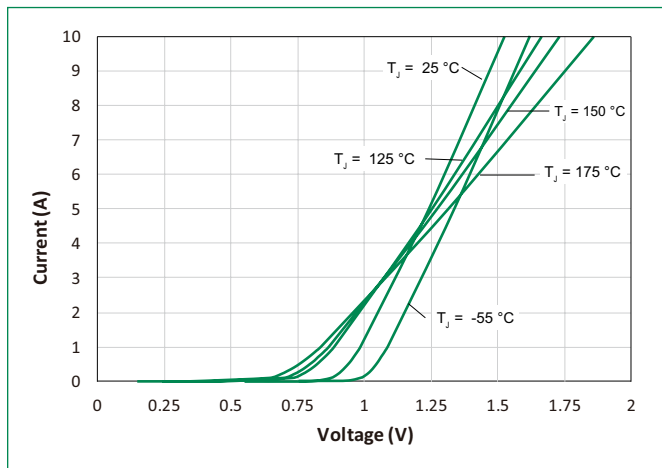


Figure 2: Typical Reverse Characteristics

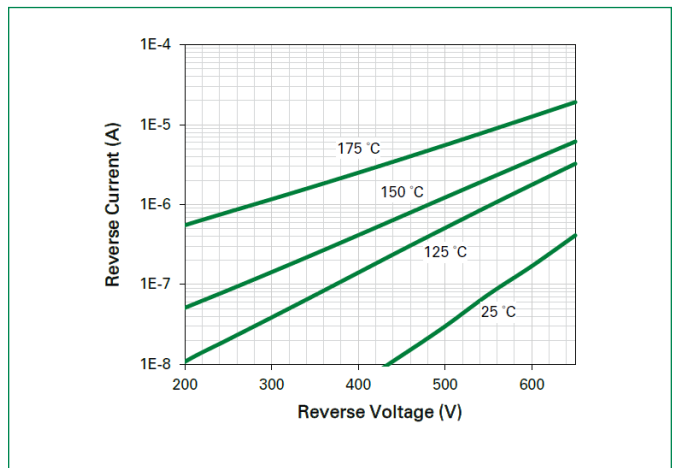


Figure 3: Power Derating

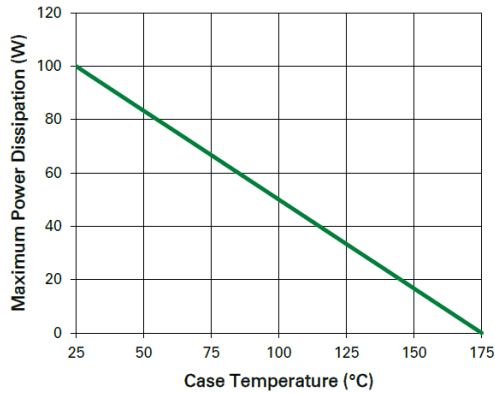


Figure 4: Current Derating

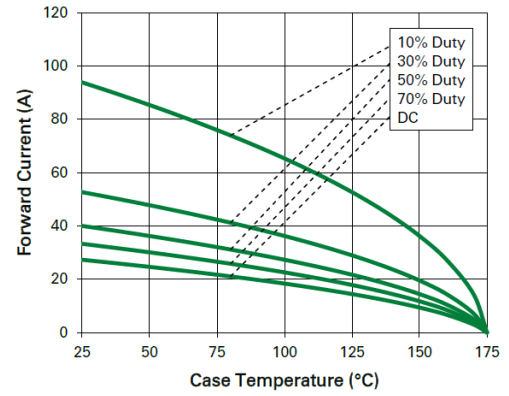


Figure 5: Capacitance vs. Reverse Voltage

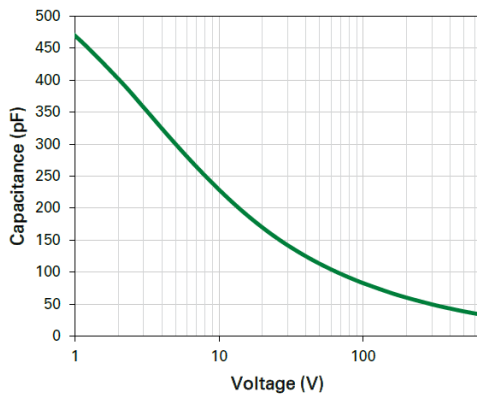


Figure 6: Capacitive Charge vs. Reverse Voltage

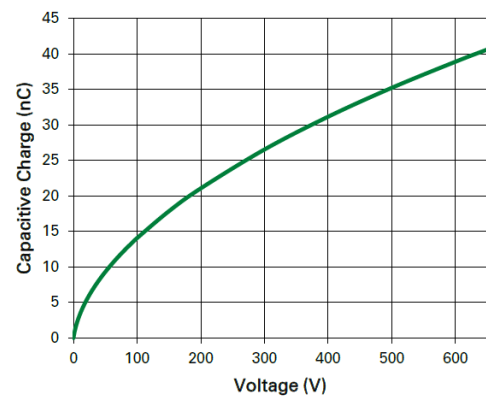


Figure 7: Stored Energy vs. Reverse Voltage

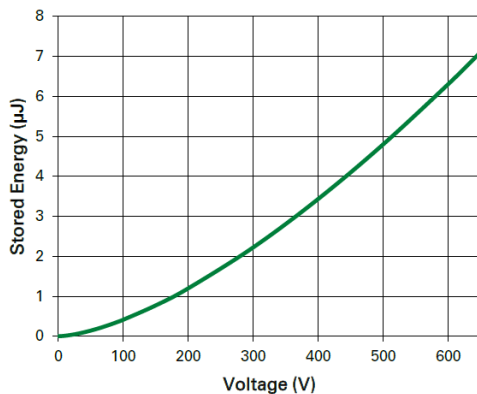
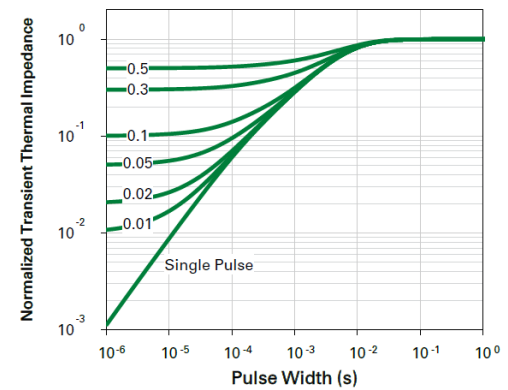


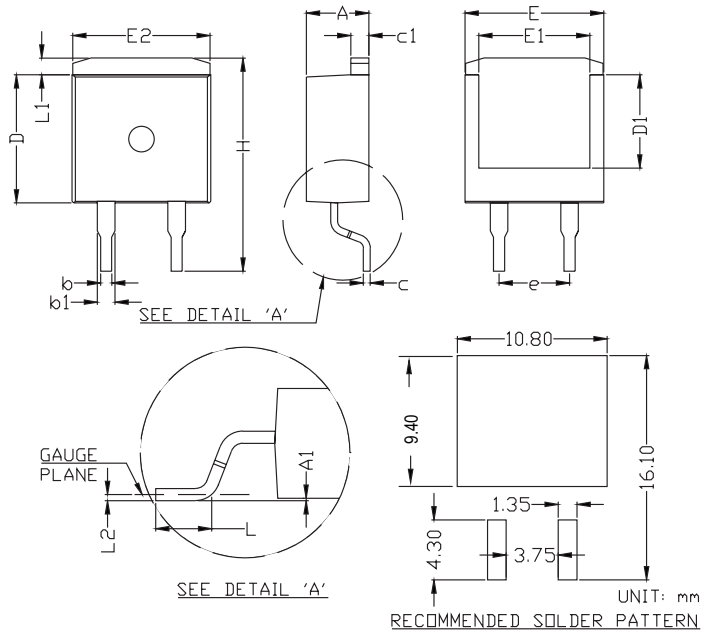
Figure 8: Transient Thermal Impedance



GEN2 SiC Schottky Diode

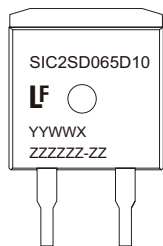
LSIC2SD065D10A, 650 V, 10 A, TO-263-2L (D2PAK)

Dimensions-Package TO-263-2L



Symbol	Millimeters		
	Min	Nom	Max
A	4.30	4.50	4.70
A1	0.00	-	0.25
b	0.70	0.80	0.90
b1	1.17	1.27	1.37
c	0.46	0.50	0.60
c1	1.25	1.30	1.40
D	9.00	9.20	9.40
D1	6.50	6.70	6.90
E	9.80	10.00	10.20
E1	7.80	8.00	8.20
E2	9.70	9.90	10.10
e	5.08 BSC		
H	15.00	15.30	15.60
L	2.00	2.30	2.60
L1	1.00	1.20	1.40
L2	0.254 BSC		

Part Numbering and Marking System

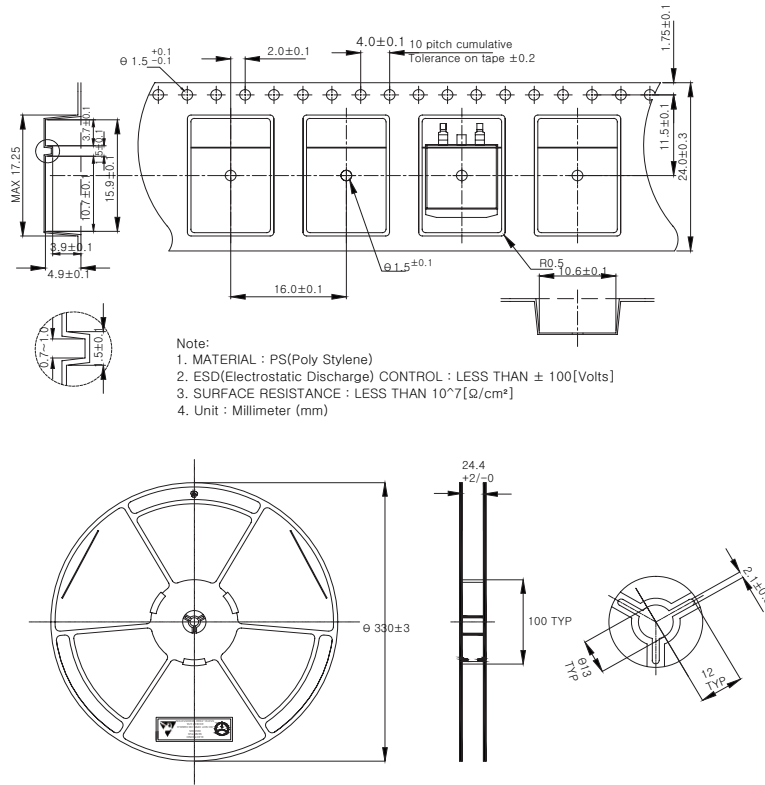


SIC = SiC Diode
 2 = Gen2
 SD = Schottky Diode
 065 = Voltage Rating (650 V)
 D = TO-263-2L (D2PAK)
 10 = Current Rating (10 A)
 YY = Year
 WW = Week
 X = Special Code
 ZZZZZZ-ZZ = Lot Number

Packing Option

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065D10A	SIC2SD065D10	Tape and Reel	800

TO-263 Carrier Reel Specifications



Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, Components intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

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